

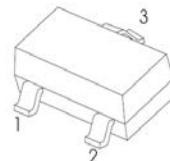


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MAITUO ELECTRONIC

## RB491D Schottky Barrier Diode



2°



### FEATURES

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability

Marking: D2E

SOT-23

### Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	Limit		Unit
Peak reverse voltage	V <sub>RM</sub>	25		V
DC reverse voltage	V <sub>R</sub>	20		V
Mean rectifying current	I <sub>F</sub>	1		A
Non-repetitive Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>	3		A
Power dissipation	P <sub>D</sub>	200		mW
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	500		°C/W
Operating Junction Temperature Range	T <sub>j</sub>	-40 ~ +125		°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150		°C

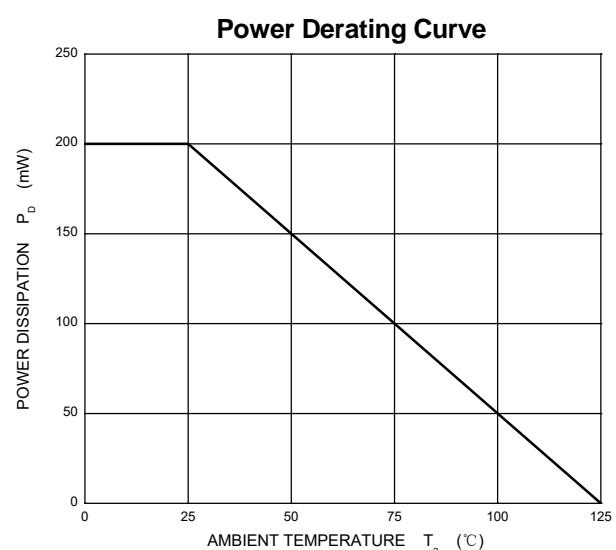
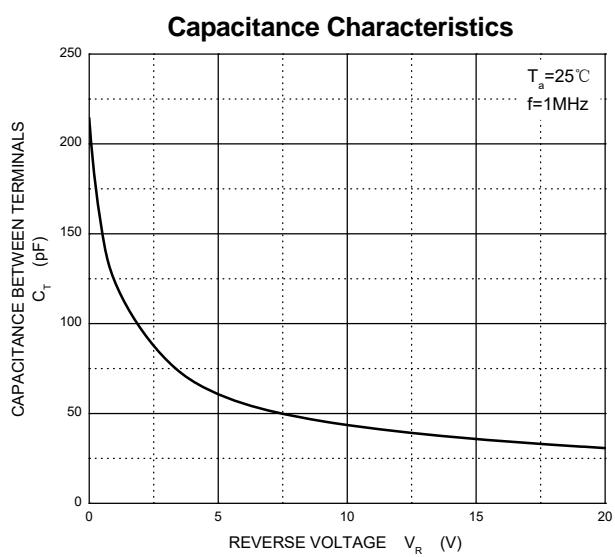
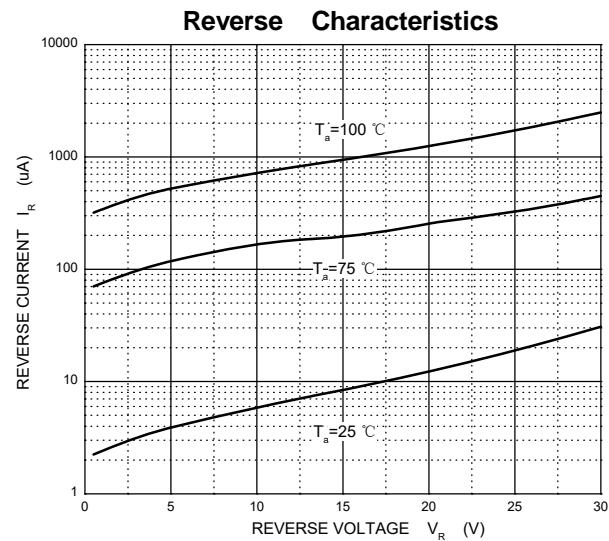
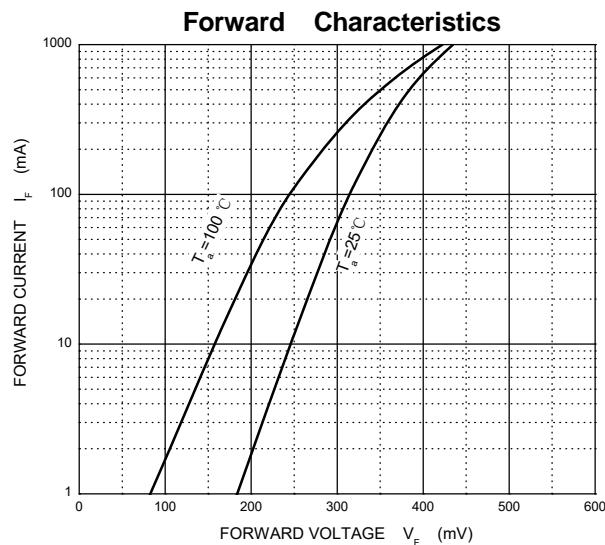
### Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V <sub>F</sub>			0.45	V	I <sub>F</sub> =1A
Reverse current	I <sub>R</sub>			200	μA	V <sub>R</sub> =20V



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## Typical Characteristics





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## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

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